imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





LX5552

2.4-2.5 GHz Front-End Module with Internally Matched Power Amplifier, LNA & SPDT Switch

PRODUCTION DATA SHEET

DESCRIPTION

fully matched InGaP/GaAs Hetero- included. junction Bipolar Transistor (HBT) power amplifier, a low noise amplifier small-signal gain of 12.5dB, low noise based on InGaAs Enhancement mode figure of 2dB, and high input thirdpseudo-morphic high mobility transistor technology, and a low-cost Depletion switch loss included. The LNA mode pHEMT (D-pHEMT) single consumes about 10mA current with pole double throw (SPDT) antenna 3.3V supply voltage. switch in a single package.

two-stage monolithic package. With 3.3V supply voltage requirements of today's provides about 26dB power gain and

LX5552 is a high-integration, high- +17dBm linear output power, with low performance WLAN front-end module total EVM (<3%) for 64QAM/ 54Mbps (FEM) for 802.11b/g/n and other OFDM. Both gain and power are applications in the 2.4-2.5GHz readily measured at antenna port with frequency range. LX5552 integrates a the insertion loss of the Tx switch

> The Rx path of LX5552 features electron order intercept point (IIP3) of +5dBm (E-pHEMT) with the insertion loss of the the Rx

LX5552 is available in a 16-pin, The Tx path of LX5552 features a 3x3mm micro-lead package (MLPQmicrowave 16L). With its high level of functional integrated circuit (MMIC) power integration, best-class performance, amplifier with active bias circuitry, compact footprint and low profile, on-chip output power detector, and LX5552 offers an ideal front-end 50Ω input/output matching inside the solution for the ever demanding design WLAN and 80mA bias current, the Tx path systems, including 802.11b/g and the latest 11n MIMO applications.

BLOCK DIAGRAM

IMPORTANT: For the most current data, consult MICROSEM's website: http://www.microsemi.com

TxIn

Det

RxOut O-

0

О

*IMN:

*OMN[.]

KEY FEATURES

- 2.4-2.5GHz 802.11b/g/n Front-End Solution in a Single MLP Package
- All RF I/O Matched to 50 Ω
- Single-Polarity 3.3V Supply
- Small Footprint: 3x3mm²
- Low Profile: 0.55mm
- RoHS Compliant & Pb-Free

TX Features :

- Power Gain ~ 26dB*
- Pout ~ +17dBm* for 3% EVM
- Current ~140mA at +17dBm
- Pout ~ +21dBm* for 11b 1Mbps DSSS Mask Compliance
- Quiescent Current ~ 80mA

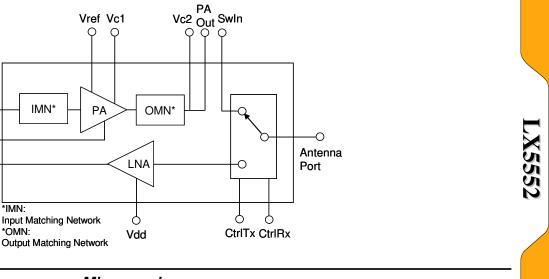
RX Features :

- Gain ~ 12.5dB*
- Noise Figure ~ 2dB*
- IIP3 ~ +5dBm*

* Including SPDT switch loss

APPLICATIONS

- IEEE 802.11b/g
- IEEE 802.11n MIMO



Copyright © 2009 Rev. 1.0, 2009-06-02



LX5552

2.4-2.5 GHz Front-End Module with Internally Matched Power Amplifier, LNA & SPDT Switch

PRODUCTION DATA SHEET

PRODUCT HIGHLIGHT **MSC** 5552 840A PACKAGE ORDER INFO Plastic MLPQ 16 pin 3x3mm LU **RoHS Compliant /Pb-Free** LX5552LU Note: Available in Tape & Reel. Append the letters "TR" to the part number. (i.e. LX5552LU-TR) ABSOLUTE MAXIMUM RATINGS PACKAGE PIN OUT Txin NC Vc1 NC (LNA)4V U U (Switch)5V Vc2 Vcc Vref PAOut Swin Det RF Input Power (With 50 Ohm Load at Output)+10dBm GND NC RxOut Maximum Junction Temperature (Tj max).....+150°C Operation Ambient Temperature-40°C to +85°C Vdd CtriRx Ant CtriTx Storage Temperature.....-65°C to +150°C RoHS/Pb-Free Peak Package Temp. for Solder Reflow LU PACKAGE ("See-Through" View from Top)

Note: Exceeding these ratings could cause damage to the device. All voltages are with respect to Ground. Currents are positive into, negative out of specified terminal.

THERMAL DATA

Plastic MLPQ 16-Pin

THERMAL RESISTANCE-JUNCTION TO CASE, θ_{JC}	9.5 C/W
THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	50.0 C/W

Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$.

The θ_{IA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

RoHS/Pb-Free 100% Matte Tin Lead finish

PACKAGE DATA



INFORMATION

Thank you for your interest in Microsemi[®] Analog Mixed Signal products.

The full data sheet for this device contains proprietary information.

To obtain a copy, please contact your local Microsemi sales representative. The name of your local representative can be obtained at the following link http://www.microsemi.com/contact/contactfind.asp

or

Contact us directly by sending an email to:

IPGdatasheets@microsemi.com

Be sure to specify the data sheet you are requesting and include your company name and contact information and or vcard.

We look forward to hearing from you.